AUTOMOTIVE GRADE

COMPLIANT

HALOGEN FREE



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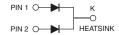
## Vishay General Semiconductor

# High Current Density Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5 \text{ A}$ 







#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 20 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	240 A			
$V_F$ at $I_F = 20$ A $(T_J = 125  ^{\circ}C)$	0.56 V			
T <sub>J</sub> max.	150 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

#### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V40PWL63C	UNIT	
Device marking code		V40PWL63C			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub> 60		V		
Maximum average forward rectified current (fig. 1)	per device	ı (1)	40	А	
	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	20	Α	
Peak forward surge current 8.3 ms single half sine-was superimposed on rated load per diode	I <sub>FSM</sub>	240	А		
Operating junction temperature range	T <sub>J</sub> <sup>(2)</sup>	-40 to +150	°C		
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C		

#### Notes

<sup>(1)</sup> With infinite heatsink

 $<sup>^{(2)}</sup>$  The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.45	-	V
	I <sub>F</sub> = 10 A			0.50	-	
	I <sub>F</sub> = 20 A			0.60	0.68	
	I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 10 A			0.43	-	
	I <sub>F</sub> = 20 A			0.56	0.63	
Reverse current per diode	V <sub>R</sub> = 60 V	T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	0.4	- mA
	v <sub>R</sub> = 60 v	T <sub>J</sub> = 125 °C		11	26	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	2350	-	pF

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V40PWL63C	UNIT	
Typical thermal resistance per device	R <sub>0JA</sub> (1)(2)	65	°C/W	
Typical thermal resistance per device	R <sub>0JM</sub> (3)	1.5		

#### Notes

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  junction to ambient
- $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  junction-to-mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	REFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BA		BASE QUANTITY	DELIVERY MODE	
V40PWM60C-M3/I	0.20	I	4500	13" diameter plastic tape and reel	
V40PWM60CHM3/I (1)	0.20	I	4500	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified



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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

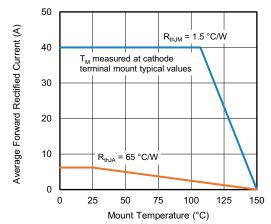


Fig. 1 - Maximum Forward Current Derating Curve

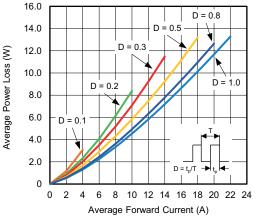


Fig. 2 - Forward Power Loss Characteristics Per Diode

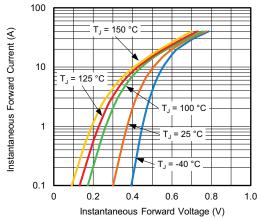


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

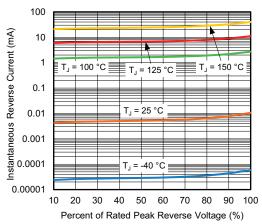


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

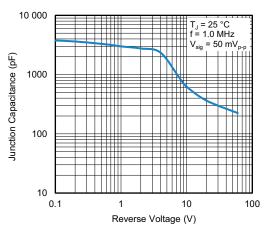


Fig. 5 - Typical Junction Capacitance Per Diode

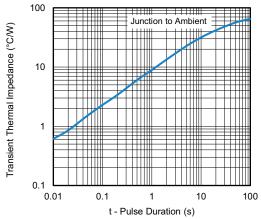


Fig. 6 - Typical Transient Thermal Impedance



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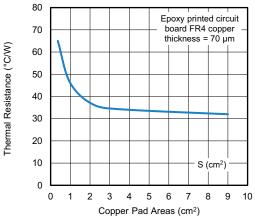
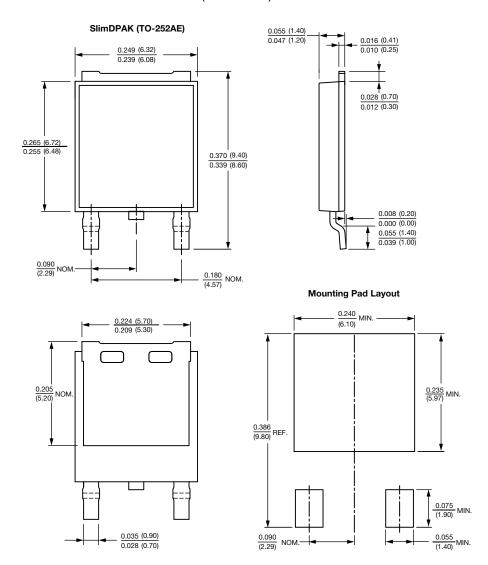


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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